

## PATENT APPLICATION

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q78162

Yoshiyuki FUKUMOTO, et al.

Appln. No.: 10/697,124

Group Art Unit: 2836

Confirmation No.: 8462

Examiner: Unknown

Filed: October 31, 2003

For: MAGNETORESISTANCE DEVICE AND METHOD OF FABRICATING THE SAME

## INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §§ 1.97 and 1.98

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure under 37 C.F.R. § 1.56, Applicant hereby notifies the U.S. Patent and Trademark Office of the documents which are listed on the attached PTO/SB/08 A & B (modified) form and/or listed herein and which the Examiner may deem material to patentability of the claims of the above-identified application.

One copy of each of the listed documents is submitted herewith.

- Japanese Laid-Open Patent Application Publication No. 2000-20922, published January 21, 2000.
- Japanese Laid-Open Patent Application Publication No. 2002-158381, published May 31, 2002.
- 3. Japanese Laid-Open Patent Application Publication No. 2001-237471, published August 31, 2001.

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- 4. Japanese Laid-Open Patent Application Publication No. 10-65232, published March 6, 1998.
- 5. Japanese Laid-Open Patent Application Publication No. 2002-74627, published March 15, 2002.
- 6. Z. Zhang et al., "Annealing effect of magnetic tunnel junctions with one FeOx layer inserted at the AI<sub>2</sub>O<sub>3</sub>/COFe interface", Applied Physics Letters, Vol. 78, No. 19, (May 7, 2001, pp. 2911-2913.
- 7. K. Matsuda et al., "Reduced magnetoresistance in magnetic tunnel junctions caused by geometrical artifacts", Applied Physics Letters, Vol. 77, No. 19, (November 6, 2000), pp. 3060-3062.
- 8. J.S. Moore et al., "Geometrically enhanced magnetoresistance in ferromagnet-insulator-ferromagnet tunnel junctions", Applied Physics Letters, Vol. 69, No. 5, (July 29, 1996), pp. 708-710.
- 9. S. Ohnuma et al., "Soft Magnetic Films with High Electrical Resistivity", Journal of the Magnetics Society of Japan, Vol. 19, No. 1, (1995), pp. 19-25 with English Abstract.

The present Information Disclosure Statement is being filed: (1) No later than three months from the application's filing date; (2) Before the mailing date of the first Office Action on the merits (whichever is later); or (3) Before the mailing date of the first Office Action after filing a request for continued examination (RCE) under §1.114, and therefore, no Statement under 37 C.F.R. § 1.97(e) or fee under 37 C.F.R. § 1.17(p) is required.

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INFORMATION DISCLOSURE STATEMENT

In compliance with the concise explanation requirement under 37 C.F.R. § 1.98(a)(3) for

foreign language documents, Applicant states that above references 1-8 are discussed within the

specification beginning at page 3, line 26, page 4, lines 2,12 and 16, page 5, line 1, page 7, lines

20 and 25, page 8, line 3.

The submission of the listed documents is not intended as an admission that any such

document constitutes prior art against the claims of the present application. Applicant does not

waive any right to take any action that would be appropriate to antedate or otherwise remove any

listed document as a competent reference against the claims of the present application.

The USPTO is directed and authorized to charge all required fees, except for the Issue

Fee and the Publication Fee, to Deposit Account No. 19-4880. Please also credit any

overpayments to said Deposit Account. A duplicate copy of this paper is attached.

Respectfully submitted,

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Date: April 1, 2004

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Substitute for Form 1449 A & B/RTO

INFORMATION DISCLOSURES

STATEMENT BY APPLICANT

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Complete if Known				
Application Number 10/697,124				
Confirmation Number	8462			
Filing Date	October 31, 2003			
First Named Inventor	Yoshiyuki FUKUMOTO			
Art Unit	2836			
Examiner Name	Unknown			
Attorney Docket Number	Q78162			

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_	U.S. PATENT DOCUMENTS						
Cite No.1	Document Number		Bublication Data				
	Number	Kind Code <sup>2</sup> (if known)	MM-DD-YYYY	Name of Patentee or Applicant of Cited Document			
	US						
	US						
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		US U	Document Number	Document Number			

	FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date	Name of Patentee or	
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation <sup>6</sup>
		JP	2000-20922	Α	01/21/2000		
		JР	2002-158381	A	05/31/2002		
		JР	2001-237471	Α	08/31/2001		
		JP	10-65232	Α	03/06/1998		
		JP	2002-74627	A	03/15/2002		
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		NON PATENT LITERATURE DOCUMENTS			
Examiner Cite Initials* No.1		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.			
		Z. Zhang et al., "Annealing effect of magnetic tunnel junctions with one FeOx layer inserted at the AI <sub>2</sub> O <sub>3</sub> /COFe interface", Applied Physics Letters, Vol. 78, No. 19, (May 7, 2001, pp. 2911-2913.			
		K. Matsuda et al., "Reduced magnetoresistance in magnetic tunnel junctions caused by geometrical artifacts", Applied Physics Letters, Vol. 77, No. 19, (November 6, 2000), pp. 3060-3062.			
		J.S. Moore et al., "Geometrically enhanced magnetoresistance in ferromagnet-insulator-ferromagnet tunnel junctions", Applied Physics Letters, Vol. 69, No. 5, (July 29, 1996), pp. 708-710.			
		S. Ohnuma et al., "Soft Magnetic Films with High Electrical Resistivity", Journal of the Magnetics Society of Japan, Vol. 19, No. 1, (1995), pp. 19-25 with English Abstract.			

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Examiner Signature	 Date Considered	J

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup>Applicant's unique citation designation number (optional). <sup>2</sup>See Kind Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or follow the hyperlink from the title of the document to the intranet. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). <sup>4</sup>For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to indicate here if English language Translation is attached.